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[5p-A301-1~19]15.4 III-V-group nitride crystals

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Tue. Sep 5, 2017 1:15 PM - 6:45 PM A301 (Main Hall)

△：奨励賞エントリー

▲：英語発表

▼：奨励賞エントリーかつ英語発表

空欄：どちらもなし

1:15 PM - 1:45 PM

[5p-A301-1][JSAP Paper Award Speech] Room-temperature continuous-wave operation of GaN-based vertical-cavity surface-emitting lasers with n-type conducting AlInN/GaN distributed Bragg reflectors

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